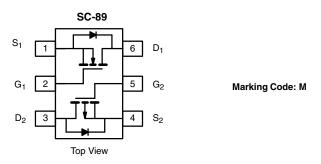


# Complementary N- and P-Channel 20 V (D-S) MOSFET

PRODUCT	PRODUCT SUMMARY					
	V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω)	I <sub>D</sub> (mA)			
	20	5 at $V_{GS}$ = 4.5 V	200			
N-Channel		7 at V <sub>GS</sub> = 2.5 V	175			
		9 at V <sub>GS</sub> = 1.8 V	150			
		10 at V <sub>GS</sub> = 1.5 V	50			
	- 20	8 at V <sub>GS</sub> = - 4.5 V	- 150			
P-Channel		12 at $V_{GS}$ = - 2.5 V	- 125			
		15 at V <sub>GS</sub> = - 1.8 V	- 100			
		20 at V <sub>GS</sub> = - 1.5 V	- 30			



Ordering Information: Si1035X-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### FEATURES

- Halogen-free According to IEC 61249-2-21
  Definition
- TrenchFET<sup>®</sup> Power MOSFET: 1.5 V Rated
- Very Small Footprint
- High-Side Switching
- Low On-Resistance: N-Channel, 5 Ω
   P-Channel, 8 Ω
- Low Threshold: ± 0.9 V (typ.)
- Fast Switching Speed: 45 ns (typ.)
- 1.5 V Operation
- Gate-Source ESD Protected: 2000 V
- Compliant to RoHS Directive 2002/95/EC

#### BENEFITS

- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

#### **APPLICATIONS**

- Replace Digital Transistor, Level-Shifter
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

ABSOLUTE MAXIMUM RAT				Channel	P-Channel			
Parameter		Symbol	5 s	Steady State	5 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	20		- 20		v	
Gate-Source Voltage		V <sub>GS</sub>		±	± 5		v	
	T <sub>A</sub> = 25 °C	1-	190	180	- 155	- 145		
Continuous Drain Current $(T_J = 150 \text{ °C})^a$	T <sub>A</sub> = 85 °C	I <sub>D</sub>	140	130	- 110	- 105		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	650		- 650		mA	
Continuous Source Current (Diode Condu	nuous Source Current (Diode Conduction)		450	380	- 450	- 380		
	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	280	250	280	250	mW	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85 °C		145	130	145	130		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150				°C	
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000				V	

Notes:

a. Surface mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.



FREE

# Si1035X

## Vishay Siliconix



Parameter	Symbol	Test Conditions		Min	Tun	Max	Unit	
Static	Symbol	lest Conditions		Min.	Тур.	Max.	Unit	
Static	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$		0.40				
Gate Threshold Voltage		$V_{DS} = V_{GS}, I_D = -250 \mu A$	N-Ch P-Ch	- 0.40			V	
			N-Ch	0.40		± 1.0		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 2.8 V$			± 0.5	± 1.0	- μΑ	
		<u> </u>			± 1.5	± 3.0		
		$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$	P-Ch		± 1.0	± 3.0		
		$V_{DS} = 16 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	N-Ch		1	500	nA	
		V <sub>DS</sub> = - 16 V, V <sub>GS</sub> = 0 V	P-Ch		- 1	- 500		
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 16 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 85 ^{\circ}\text{C}$	N-Ch			10		
		$V_{DS}$ = - 16 V, $V_{GS}$ = 0 V, $T_{J}$ = 85 °C	P-Ch			- 10	μA	
		$V_{DS} = 5 V, V_{GS} = 4.5 V$	N-Ch	250			<u> </u>	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = - 5 V, V <sub>GS</sub> = - 4.5 V	P-Ch	- 200			mA	
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 200 mA	N-Ch			5	-	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 150 mA	P-Ch			8		
		V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 175 mA	N-Ch			7		
		V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = 125 mA	P-Ch			12	Ω	
		V <sub>GS</sub> = 1.8 V, I <sub>D</sub> = 150 mA	N-Ch			9		
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 100 mA	P-Ch			15	-	
		$V_{DS} = 1.5 \text{ V}, I_D = 40 \text{ mA}$	N-Ch			10		
		V <sub>DS</sub> = - 1.5 V, I <sub>D</sub> = - 30 mA	P-Ch			20		
		V <sub>DS</sub> = 10 V, I <sub>D</sub> = 200 mA	N-Ch		0.5		s	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 150 mA	P-Ch		0.4			
		I <sub>S</sub> = 150 mA, V <sub>GS</sub> = 0 V	N-Ch			1.2	v	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 150 mA, V <sub>GS</sub> = 0 V	P-Ch			- 1.2		
Dynamic <sup>b</sup>								
-			N-Ch		750			
Total Gate Charge	Qg	N-Channel			1500		]	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 150 \text{ mA}$	N-Ch		75		pC	
Gale-Source Charge	∝gs	P-Channel	P-Ch		150			
Gate-Drain Charge	Q <sub>qd</sub>	$V_{DS}$ = - 10 V, $V_{GS}$ = - 4.5 V, $I_D$ = - 150 mA	N-Ch		225			
··· - ·· 3-	gu		P-Ch		450			
Turn-On Time	t <sub>ON</sub>	N-Channel V <sub>DD</sub> = 10 V, R <sub>L</sub> = 47 $\Omega$	N-Ch			75		
		$\text{I}_\text{D}\cong$ 250 mA, $\text{V}_\text{GEN}$ = 4.5 V, $\text{R}_\text{g}$ = 10 $\Omega$	P-Ch			80	-	
Turn-Off Time		P-Channel V <sub>DD</sub> = - 10 V, R <sub>I</sub> = 65 Ω	N-Ch			75	- ns	
	t <sub>OFF</sub>	$I_D \cong$ - 150 mA, $V_{GEN} =$ - 4.5 V, $R_g =$ 10 $\Omega$	P-Ch			90		

Notes:

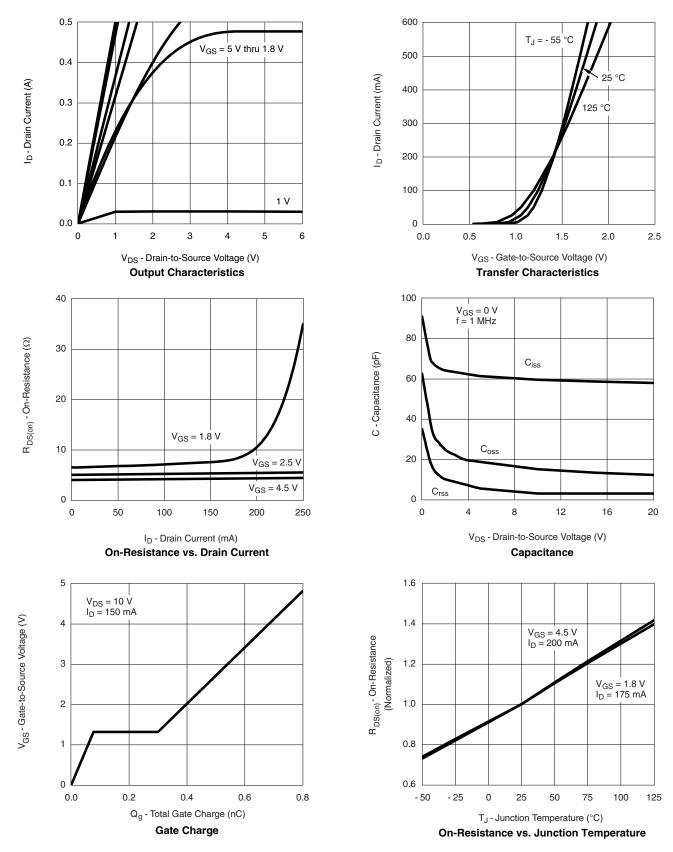
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

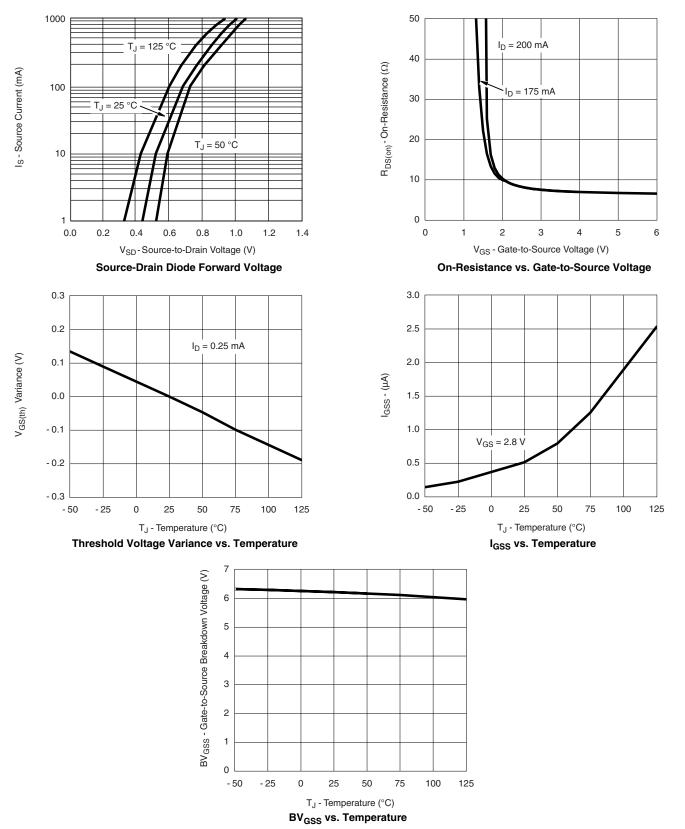


#### **N-CHANNEL TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



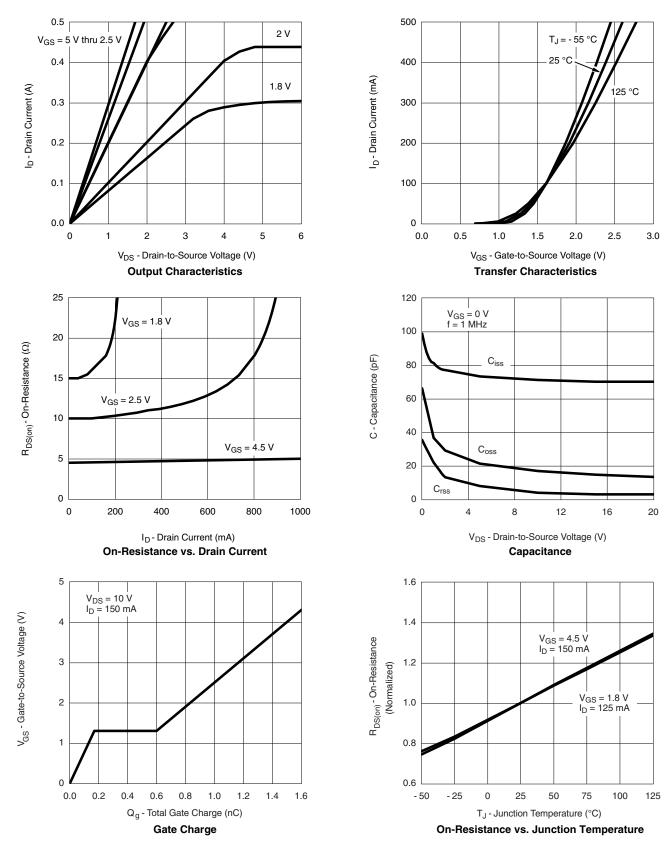
Document Number: 71426 S10-2544-Rev. C, 08-Nov-10

### **N-CHANNEL TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



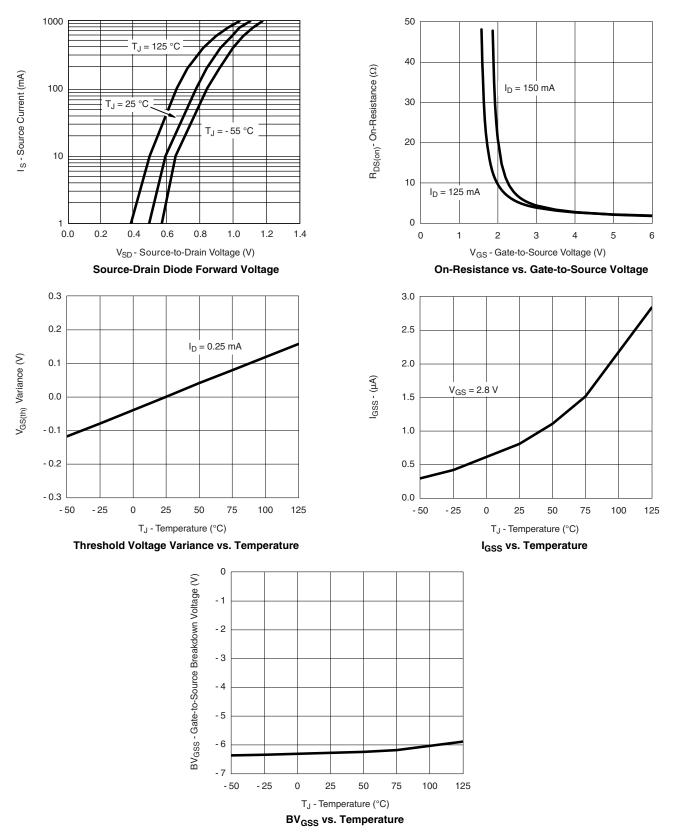


#### **P-CHANNEL TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



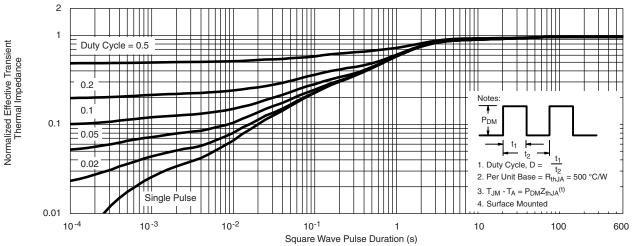
Document Number: 71426 S10-2544-Rev. C, 08-Nov-10

#### **P-CHANNEL TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)





#### N- OR P-CHANNEL TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?71426">www.vishay.com/ppg?71426</a>.



## SC-89 6-Leads (SOT-563F)



Notes

- 1. Dimensions in millimeters.
- Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

A Datums A, B and D to be determined 0.10 mm from the lead tip.

 $\triangle$  Terminal numbers are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.









DIM.	MILLIMETERS					
	MIN.	NOM.	MAX.			
А	0.56	0.58	0.60			
A1	0	0.02	0.10			
b	0.15	0.22	0.30			
С	0.10	0.14	0.18			
D	1.50	1.60	1.70			
E	1.50	1.60	1.70			
E1	1.15	1.20	1.25			
е	0.45	0.50	0.55			
e1	0.95	1.00	1.05			
L	0.25	0.35	0.50			
L1	0.10	0.20	0.30			
C14-0439-Rev DWG: 5880	v. C, 11-Aug-14					

Revision: 11-Aug-14

1 For technical questions, contact: <u>analogswitchtechsupport@vishay.com</u> Document Number: 71612

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# Application Note 826

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#### **RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)

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